



P-Channel 60-V (D-S) MOSFET

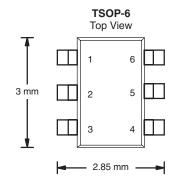
PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)		
- 60	0.220 at V _{GS} = - 10 V	± 2.2		
	0.310 at V _{GS} = - 4.5 V	± 1.9		

FEATURES

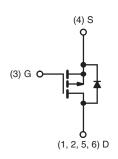
- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET
- Compliant to RoHS Directive 2002/95/EC



FREE



Ordering Information: Si3459DV-T1-E3 (Lead (Pb)-free)
Si3459DV-T1-GE3 (Lead (Pb)-free and Halogen-free)



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS $T_A =$	25 °C, unless othe	rwise noted			
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	- 60	V	
Gate-Source Voltage		V _{GS}	± 20		
Continuous Drain Current (T _{.I} = 150 °C) ^{a, b}	T _C = 25 °C	I _D	± 2.2		
Continuous Drain Current (T _J = 150 °C)	T _C = 70 °C	טי [± 1.7		
Pulsed Drain Current		I _{DM}	± 10	A	
Single Avalanche Current (L = 0.1 mH)		I _{AS}	- 7	1	
Mariana Barra Birainatian b	T _A = 25 °C	P _D	2	W	
Maximum Power Dissipation ^b	T _A = 70 °C	7 'U F	1.3	, vv	
Operating Junction and Storage Temperature Range		T _J , T _{sta}	- 55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^a	t ≤ 5 s	- R _{thJA}		62.5	
	Steady State		106		°C/W
Maximum Junction-to-Lead	Steady State	R_{thJL}	35		

Notes

a. Surface Mounted on FR4 board.

 $b.\ t\leq 5\ s.$

Si3459DV

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SPECIFICATIONS T _J = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	- 60			V	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 1				
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -60 \text{ V}, V_{GS} = 0 \text{ V}$ $V_{DS} = -60 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 150 ^{\circ}\text{C}$			- 1	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = -60 \text{ V}, V_{GS} = 0 \text{ V}, V_{J} = 150 \text{ C}$ $V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$	- 10		- 50	Α	
	D	V _{GS} = - 10 V, I _D = - 2.2 A		0.190	0.220	Ω	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 4.5 V, I _D = - 1.9 A		0.265	0.310		
Forward Transconductance ^a	9 _{fs}	$V_{DS} = -4.5 \text{ V}, I_{D} = -2.2 \text{ A}$		4		S	
Dynamic ^b							
Total Gate Charge	Qg			7	14	nC	
Gate-Source Charge	Q_{gs}	$V_{DS} = -30 \text{ V}, V_{GS} = -10 \text{ V}, I_{D} = -2.2 \text{ A}$		1.6			
Gate-Drain Charge	Q _{gd}			1.2			
Turn-On Delay Time	t _{d(on)}			8	16		
Rise Time	t _r	$V_{DD} = -30 \text{ V}, R_L = 30 \Omega$ $I_D \cong -1 \text{ A}, V_{GEN} = -10 \text{ V}, R_g = 6 \Omega$		12	24	ns	
Turn-Off DelayTime	t _{d(off)}			23	45		
Fall Time	t _f	7		12	25		
Source-Drain Rating Characteristics ^b							
Continuous Current	I _S				- 1.7	Α	
Pulsed Current	I _{SM}				- 10		
Diode Forward Voltage ^a	V _{SD}	I _S = - 1.7 A, V _{GS} = 0 V	_	- 0.8	- 1.2	V	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 1.7 A, dI/dt = 100 A/μs	_	50	90	ns	

Notes:

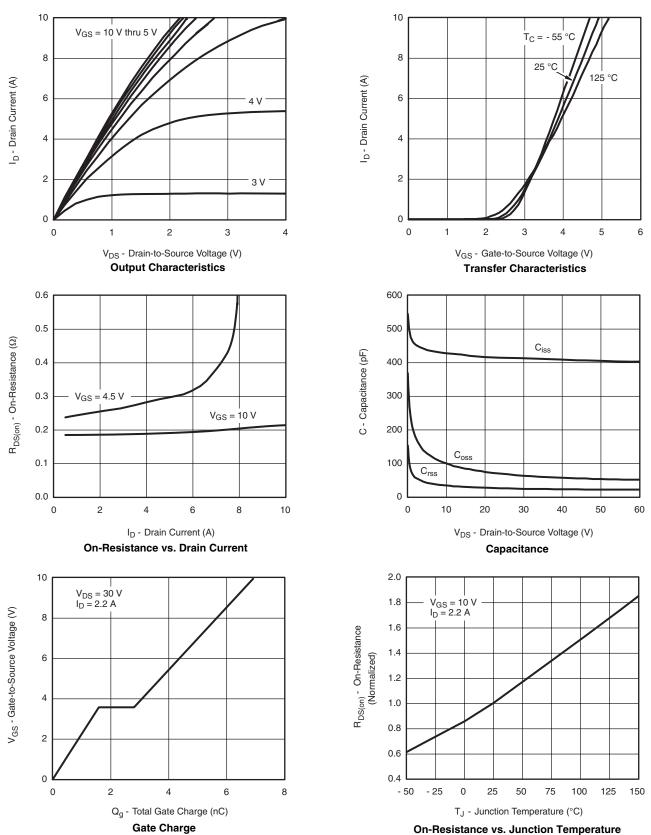
- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.





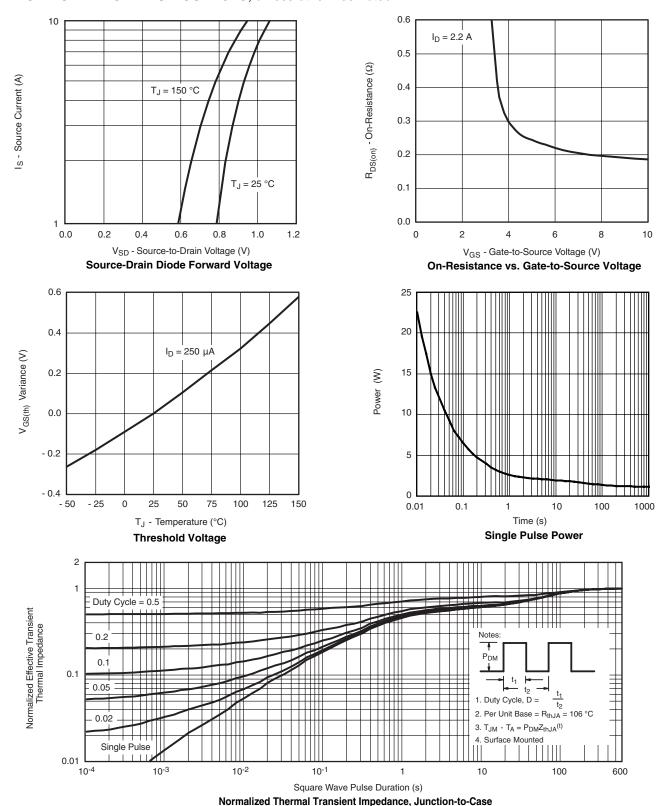
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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